## NSN 5961-00-436-0955

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-436-0955 **Inclosure Material:** Metal **Overall Length:** 1.519 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 milliamperes source cutoff current and 1.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 88.0 watts small-signal input power, common-collector **Transfer Ratio:** 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** No

## **NSN 5961-00-436-0955** Transistor - Page 2 of 2



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